

An anomalous dip in thermoelectric power of $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_{7-\delta}$

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Abstract

The thermoelectric power, S , has been studied for sintered samples of $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_{7-\delta}$ with $0 \leq x \leq 0.30$ in the temperature range from the superconducting T_c to room temperature. S increases with decreasing temperature, and has a broad maximum at T^{max} in the region around 120 K before decreasing strongly when T_c is approached. Several properties indicate a decrease of charge concentration with decreasing doping, x , from $S(x, 290\text{K})$, T^{max} , and the resistivity $\rho(x, 290\text{K})$. An anomaly has been observed in $S(T)$ for $x \geq 0.20$ in the form of a dip at 78 K of order 15% of S . The origin of this feature is not known.

Key words: Superconductivity ;Thermoelectric power ;Pr doping ;

1. Introduction

In the RE-123 (RE=rare earth element) superconductors the RE's can be exchanged for each other with only small effect on the critical temperature T_c with the exception of Pr substitution which decreases T_c dramatically. Different explanations [1–4] for the depression of T_c have been suggested. Varying results for the valence of Pr is one reason. Recent neutron diffraction results in Nd(Pr)-123 [5] and analysis of T_c in Y(Pr)-123 [6] have suggested that hole localisation in the Pr^{4+} site is the main reason for the suppression of superconductivity by Pr. The observation of superconductivity in single crystals of $\text{PrBa}_2\text{Cu}_3\text{O}_{7-\delta}$ [7,8] further complicates the understanding of the role played by Pr in the suppression of T_c . In our previous work [5], resistivity measurements in $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_7$ showed a decreasing metallic behaviour with increased resistivity and decreased slope of the normal state resistivity vs. temperature with increasing x . Neutron diffraction data indicated that the Cu1-O4 and Cu2-O4 distances and the oxygen content were independent of Pr doping in Nd(Pr)-123. Bond Valence Sum (BVS) calculations showed a constant Cu2 valence but a decrease of the

total hole concentration in the CuO_2 plane. To further investigate the effect of Pr in $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_{7-\delta}$ system, we have measured the thermoelectric power $S(x, T)$.

2. Sample characterisation and experimental

Samples of $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_{7-\delta}$ (with $x = 0, 0.05, 0.10, 0.15, 0.20$, and 0.30) were prepared by standard solid-state methods. Starting materials were high purity Nd_2O_3 , BaCO_3 , CuO , and Pr_6O_{11} . The samples were pressed into pellets and calcinated in air at 900, 920, and 920 °C with intermediate grindings. They were then annealed in flowing oxygen at 460 °C for 3 days and the temperature was finally decreased to room temperature at a rate of 12 °C/hr.

The samples were characterised by X-ray powder diffraction (XRD). The XRD patterns were recorded in a Guinier-Hägg focusing camera using $\text{CuK}\alpha$ radiation with Si as an internal standard [9]. The XRD results for Pr-doped Nd-123 samples displayed single-phase behaviour. All XRD patterns were indexed with an orthorhombic unit cell.

The electrical resistivity was measured with a standard dc four-probe method. Electrical leads were at-

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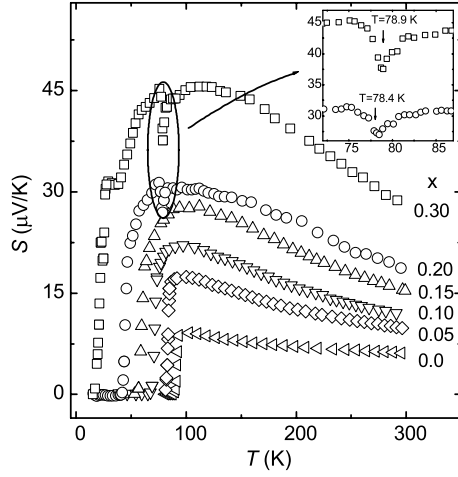


Fig. 1. Thermoelectric power S as a function of temperature and Pr doping for $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_{7-\delta}$. Inset: $S(T)$ in the temperature range 72-87 K, where an anomaly has been observed in the form a dip, for $x=0.20$ and 0.30 .

tached to the sample by silver paint and heat treated at 300 °C in flowing oxygen for half an hour, which gave contact resistances of order 1-2 Ω . Thermoelectric power measurements were made on sintered bars of typical dimensions $0.5 \times 2.5 \times 10 \text{ mm}^3$, using a small, reversible temperature difference of 1.5 K.

3. Results and discussion

Figure 1 shows the thermoelectric power S as a function of temperature and Pr concentration for $\text{Nd}_{1-x}\text{Pr}_x\text{Ba}_2\text{Cu}_3\text{O}_{7-\delta}$. S first increases with increasing temperature towards a broad maximum at T^{max} above the superconducting T_c , and then decreases up to room temperature. Both S and T^{max} increase with increasing x . As further illustrated in the inset of Fig. 1, a dip in $S(T)$ was observed at a temperature in the range 78-79 K. This feature only occurred for $x \geq 0.20$. These anomalies are reproducible. The origin of the anomaly is not known. Except for the dips, all studied properties of the samples with $x \geq 0.20$ (e.g. $S(290\text{K})$, $\rho(290\text{K})$, T_c , T^{max} , and BVS calculations) are in agreement with the trends expected from the results for $x < 0.20$.

The doping concentration dependence of the room temperature $S(290\text{K})$ and resistivity $\rho(290\text{K})$ are plotted in Fig. 2. Both $S(290\text{K})$ and $\rho(290\text{K})$ show a continuous increase with increasing Pr doping. The results for $S(290\text{K})$, T^{max} , and $\rho(290\text{K})$ suggest that Pr reduces hole concentration in the CuO_2 plane. This is well in agreement with BVS calculations from neutron diffraction data [5].

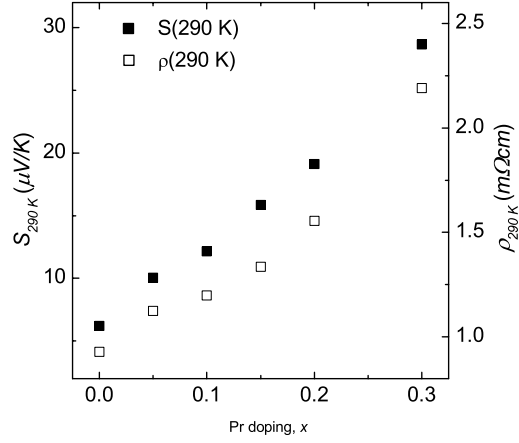


Fig. 2. $S(290\text{K})$ (left scale) and $\rho(290\text{K})$ (right scale) vs. Pr doping, x .

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